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R1LP5256E Series

256Kb Advanced LPSRAM (32k word x 8bit)

R10DS0070EJ0100
Rev.1.00
2011.04.13

Description

The R1LP5256E Series is a family of low voltage 256-Kbit static RAMs organized as 32,768-word by 8-bit, fabricated by Renesas's high-performance 0.15um CMOS and TFT technologies. The R1LP5256E Series has realized higher density, higher performance and low power consumption. The R1LP5256E Series is suitable for memory applications where a simple interfacing, battery operating and battery backup are the important design objectives. It has been packaged in 28-pin SOP and 28-pin TSOP.

Features

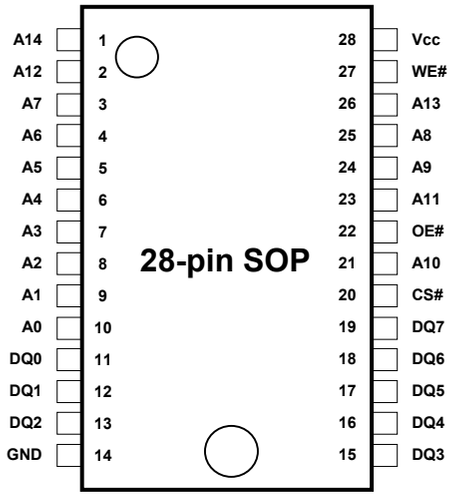
- Single 4.5V~5.5V power supply
- Small stand-by current: 1µA (5.0V, typical)
- No clocks, No refresh
- All inputs and outputs are TTL compatible.
- Easy memory expansion by CS#
- Common Data I/O
- Three-state outputs: OR-tie Capability
- OE# prevents data contention on the I/O bus

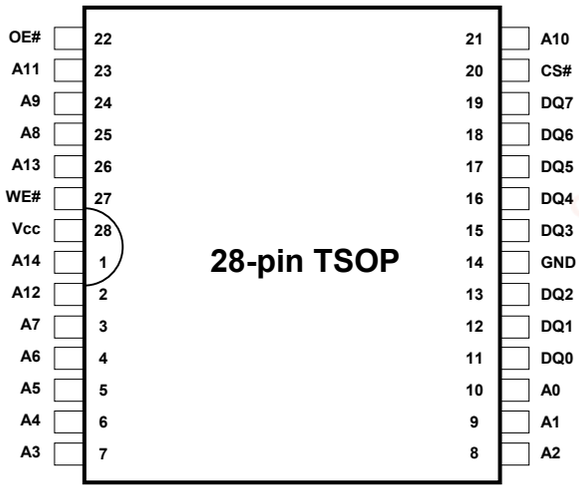
Ordering Information

Orderable Part Name	Access time	Temperature Range	Package	Shipping Container	Quantity
R1LP5256ESP-5SR#B0	55 ns	0 ~ +70°C	450-mil 28-pin plastic SOP PRSP0028DB-B (28P2W-C)	Tube	Max. 30pcs/Tube Max. 300pcs/Inner Bag Max. 1200pcs/Inner Box
R1LP5256ESP-5SI#B0		-40 ~ +85°C			
R1LP5256ESP-7SR#B0	70 ns	0 ~ +70°C			
R1LP5256ESP-7SI#B0		-40 ~ +85°C			
R1LP5256ESP-5SR#S0	55 ns	0 ~ +70°C		Embossed tape	1000pcs/Reel
R1LP5256ESP-5SI#S0		-40 ~ +85°C			
R1LP5256ESP-7SR#S0	70 ns	0 ~ +70°C			
R1LP5256ESP-7SI#S0		-40 ~ +85°C			
R1LP5256ESA-5SR#B0	55 ns	0 ~ +70°C	8mm×13.4mm 28-pin plastic TSOP (normal-bend type) PTSA0028ZA-A (28P2C-A)	Tray	Max. 234pcs/Tray Max. 1872pcs/Inner Box
R1LP5256ESA-5SI#B0		-40 ~ +85°C			
R1LP5256ESA-7SR#B0	70 ns	0 ~ +70°C			
R1LP5256ESA-7SI#B0		-40 ~ +85°C			
R1LP5256ESA-5SR#S0	55 ns	0 ~ +70°C		Embossed tape	1000pcs/Reel
R1LP5256ESA-5SI#S0		-40 ~ +85°C			
R1LP5256ESA-7SR#S0	70 ns	0 ~ +70°C			
R1LP5256ESA-7SI#S0		-40 ~ +85°C			

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Pin Arrangement



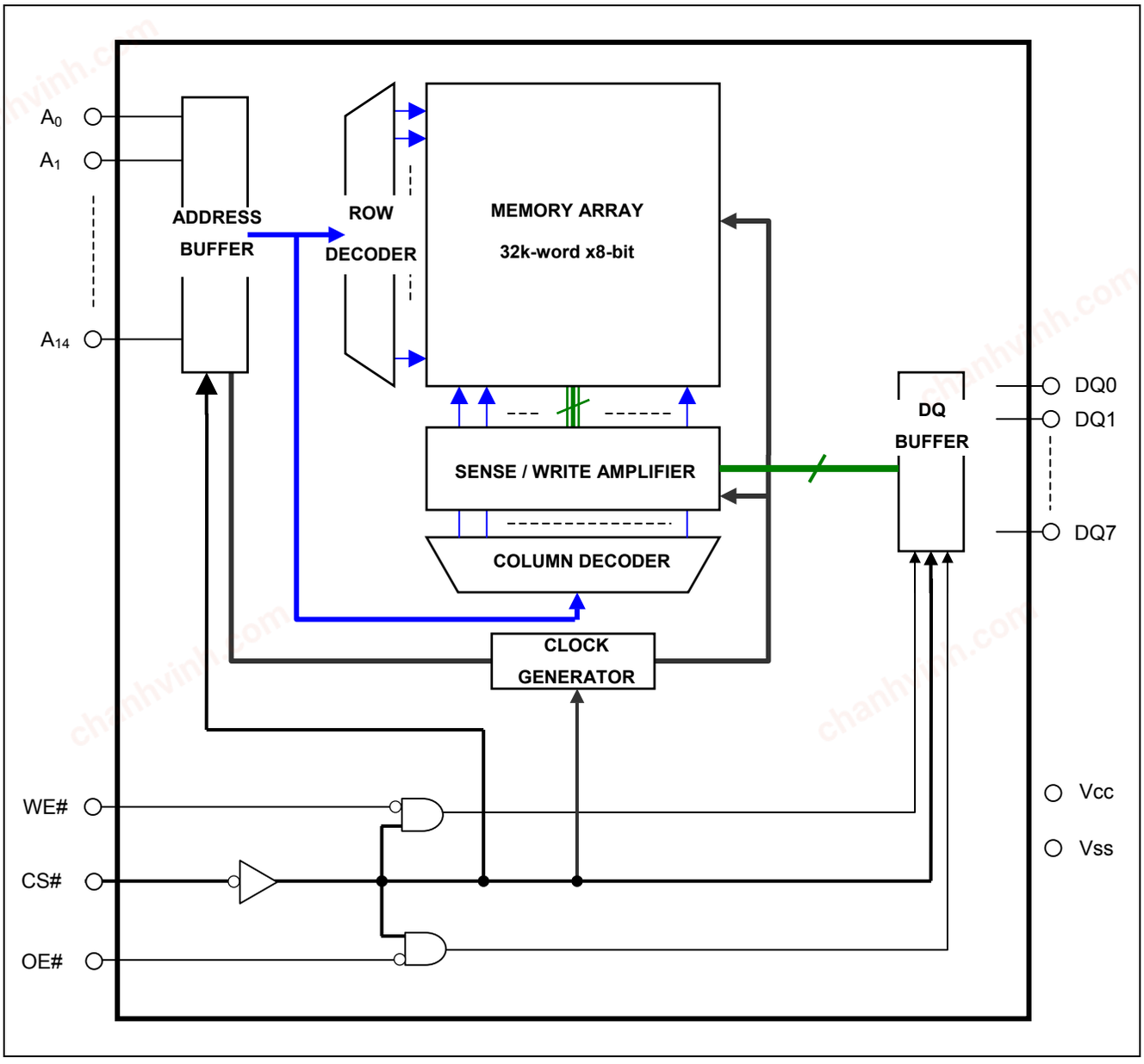


Pin Description

Pin name	Function
Vcc	Power supply
Vss	Ground
A0 to A14	Address input
DQ0 to DQ7	Data input/output
CS#	Chip select
WE#	Write enable
OE#	Output enable

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Block Diagram



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Operation Table

CS#	WE#	OE#	DQ0~7	Operation
H	X	X	High-Z	Stand-by
L	L	X	Din	Write
L	H	L	Dout	Read
L	H	H	High-Z	Output disable

Note 1. H: V_{IH} L:V_{IL} X: V_{IH} or V_{IL}

Absolute Maximum

Parameter	Symbol	Value		unit
Power supply voltage relative to Vss	Vcc	-0.3 to +7		V
Terminal voltage on any pin relative to Vss	V_T	-0.3[*1] to Vcc+0.3[*2]		V
Power dissipation	P_T	0.7		W
Operation temperature	Topr[*3]	R Ver.	0 to +70	°C
		I Ver.	-40 to +85	
Storage temperature range	Tstg	-65 to 150		°C
Storage temperature range under bias	Tbias[*3]	R Ver.	0 to +70	°C
		I Ver.	-40 to +85	

Note 1. –3.0V for pulse ≤ 30ns (full width at half maximum)
2. Maximum voltage is +7V.
3. Ambient temperature range depends on R/I-version. Please see table on page 1.

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DC Operating Conditions

Parameter		Symbol	Min.	Typ.	Max.	Unit	Note
Supply voltage		Vcc	4.5	5.0	5.5	V	
		Vss	0	0	0	V	
Input high voltage		V_{IH}	2.2	-	Vcc+0.3	V	
Input low voltage		V_{IL}	-0.3	-	0.8	V	1
Ambient temperature range	R Ver.	Ta	0	-	+70	°C	2
	I Ver.		-40	-	+85	°C	2

Note 1. –3.0V for pulse ≤ 30ns (full width at half maximum)
2. Ambient temperature range depends on R/I-version. Please see table on page 1.

DC Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions	
Input leakage current	$\lvert I_{LI} \rvert$	-	-	1	µA	Vin = Vss to Vcc	
Output leakage current	$\lvert I_{LO} \rvert$	-	-	1	µA	CS# =V_{IH} or OE# =V_{IH}, VI/O =Vss to Vcc	
Average operating current	I_{CC1}	-	25	35	mA	Min. cycle, duty =100%, II/O = 0mA CS# =V_{IL}, Others = V_{IH}/V_{IL}	
	I_{CC2}	-	2	4	mA	Cycle =1µs, duty =100%, II/O = 0mA CS# ≤ 0.2V, V_{IH} ≥ Vcc-0.2V, V_{IL} ≤ 0.2V	
Standby current	I_{SB}	-	-	3	mA	CS# =V_{IH}, Others = Vss to Vcc	
Standby current	I_{SB1}	-	1*1	2	µA	~+25°C	Vin = Vss to Vcc
		-	-	3	µA	~+40°C	CS# ≥ Vcc-0.2V
		-	-	8	µA	~+70°C	
		-	-	10	µA	~+85°C	
Output high voltage	V_{OH}	2.4	-	-	V	I_{OH} = -1mA	
	V_{OH2}	Vcc - 0.5	-	-	V	I_{OH} = -0.1mA	
Output low voltage	V_{OL}	-	-	0.4	V	I_{OL} = 2mA	

Note 1. Typical parameter indicates the value for the center of distribution at 5.0V (Ta= 25ºC), and not 100% tested.

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Capacitance

(Vcc = 4.5V ~ 5.5V, f = 1MHz, Ta = 0 ~ +70°C / -40 ~ +85°C[*2])

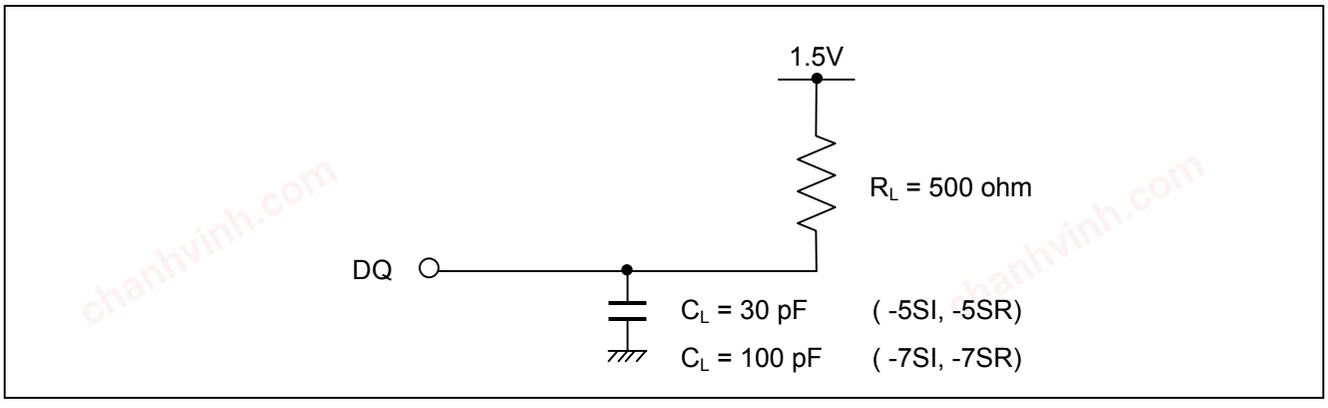
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions	Note
Input capacitance	C in	-	-	6	pF	Vin =0V	1
Input / output capacitance	$C_{I/O}$	-	-	8	pF	VI/O =0V	1

Note 1. This parameter is sampled and not 100% tested.
2. Ambient temperature range depends on R/I-version. Please see table on page 1.

AC Characteristics

Test Conditions (Vcc = 4.5V ~ 5.5V, Ta = 0 ~ +70°C / -40 ~ +85°C[*1])

- Input pulse levels: VIL = 0.6V, VIH = 2.4V
- Input rise and fall time: 5ns
- Input and output timing reference level: 1.5V
- Output load: See figures (Including scope and jig)



Note 1. Ambient temperature range depends on R/I-version. Please see table on page 1.

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Read Cycle

Parameter	Symbol	R1LP5256E**-5S*		R1LP5256E**-7S*		Unit	Note
		Min.	Max.	Min.	Max.		
Read cycle time	t_{RC}	55	-	70	-	ns	
Address access time	t_{AA}	-	55	-	70	ns	
Chip select access time	t_{ACS}	-	55	-	70	ns	
Output enable to output valid	t_{OE}	-	30	-	35	ns	
Output hold from address change	t_{OH}	10	-	10	-	ns	
Chip select to output in low-Z	t_{CLZ}	5	-	5	-	ns	2,3
Output enable to output in low-Z	t_{OLZ}	5	-	5	-	ns	2,3
Chip deselect to output in high-Z	t_{CHZ}	0	20	0	25	ns	1,2,3
Output disable to output in high-Z	t_{OHZ}	0	20	0	25	ns	1,2,3

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Write Cycle

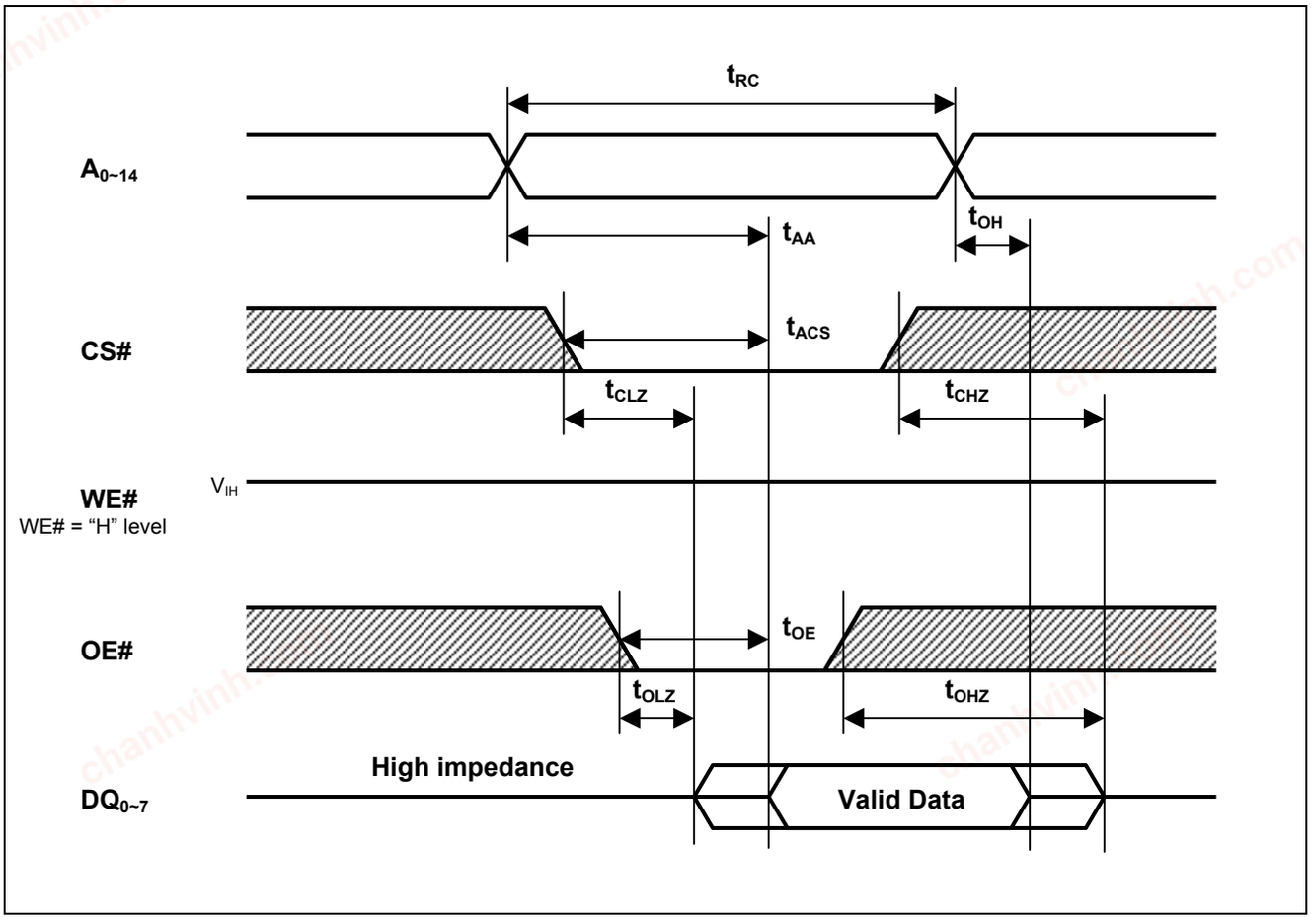
Parameter	Symbol	R1LP5256E**-5S*		R1LP5256E**-7S*		Unit	Note
		Min.	Max.	Min.	Max.		
Write cycle time	t_{WC}	55	-	70	-	ns	
Address valid to end of write	t_{AW}	50	-	65	-	ns	
Chip select to end of write	t_{CW}	50	-	65	-	ns	5
Write pulse width	t_{WP}	40	-	50	-	ns	4
Address setup time	t_{AS}	0	-	0	-	ns	6
Write recovery time	t_{WR}	0	-	0	-	ns	7
Data to write time overlap	t_{DW}	25	-	30	-	ns	
Data hold from write time	t_{DH}	0	-	0	-	ns	
Output enable from end of write	t_{OW}	5	-	5	-	ns	2
Output disable to output in high-Z	t_{OHZ}	0	20	0	25	ns	1,2
Write to output in high-Z	t_{WHZ}	0	20	0	25	ns	1,2

Note
1. t_{CHZ}, t_{OHZ} and t_{WHZ} are defined as the time at which the outputs achieve the open circuit conditions and are not referred to output voltage levels.
2. This parameter is sampled and not 100% tested.
3. At any given temperature and voltage condition, t_{HZ} max is less than t_{LZ} min both for a given device and from device to device.
4. A write occurs during the overlap of a low CS#, a low WE#.
   A write begins at the latest transition among CS# going low and WE# going low.
   A write ends at the earliest transition among CS# going high and WE# going high.
   t_{WP} is measured from the beginning of write to the end of write.
5. t_{CW} is measured from the later of CS# going low to end of write.
6. t_{AS} is measured the address valid to the beginning of write.
7. t_{WR} is measured from the earliest of CS# or WE# going high to the end of write cycle.
8. Don't apply inverted phase signal externally when DQ pin is output mode.

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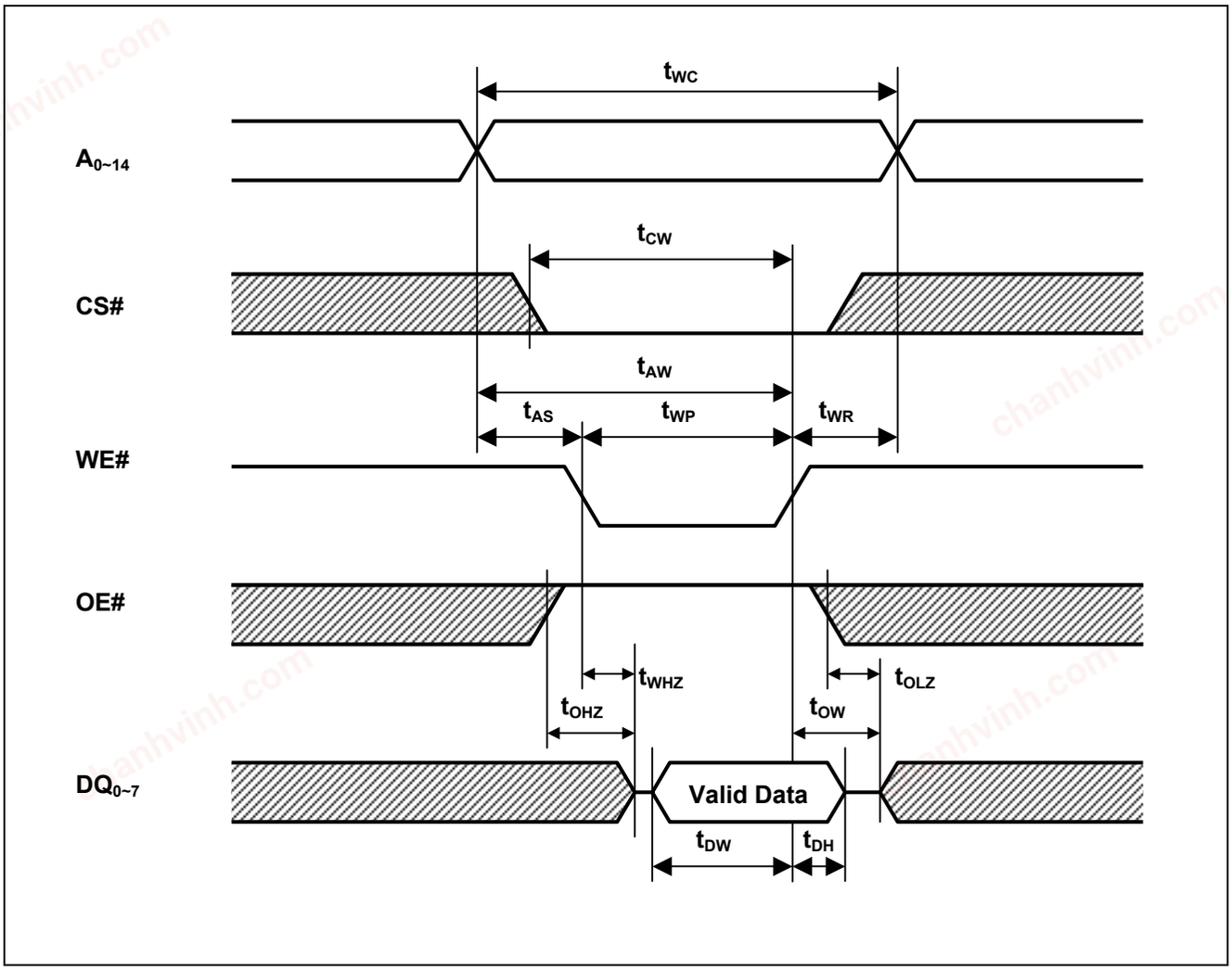
Timing Waveforms

Read Cycle



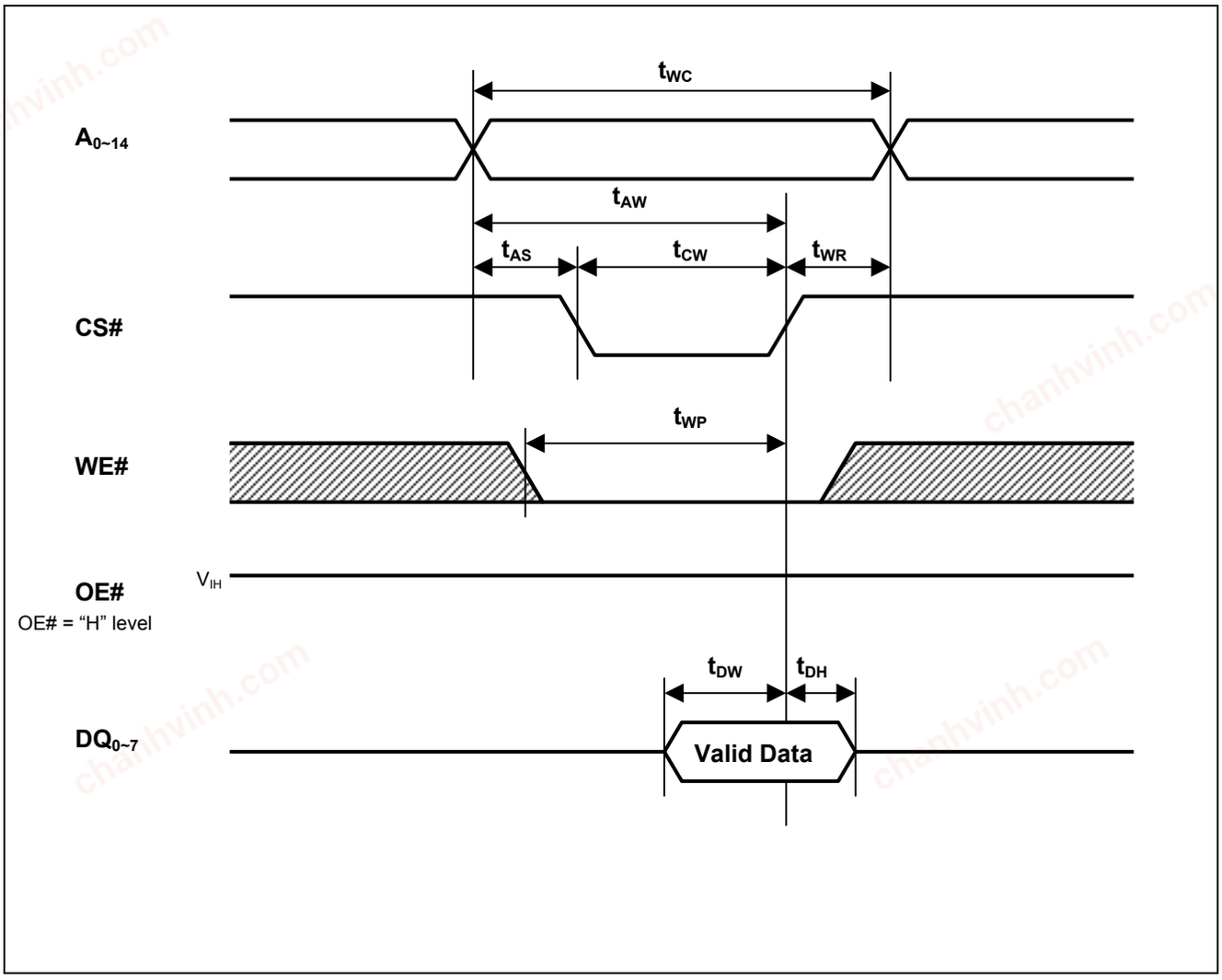
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Write Cycle (1) (WE# CLOCK)



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Write Cycle (2) (CS# CLOCK)



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Low Vcc Data Retention Characteristics

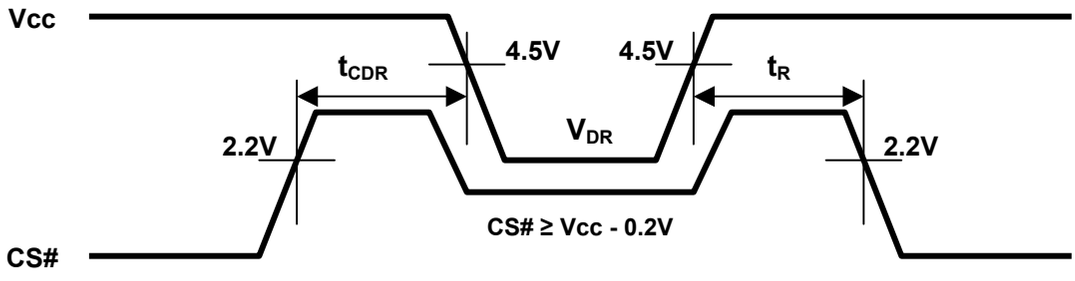
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions[*2]	
V_{CC} for data retention	V_{DR}	2.0	-	5.5	V	Vin ≥ 0V CS# ≥ Vcc-0.2V	
Data retention current	I_{CCDR}	-	1[*1]	2	µA	~+25°C	Vcc=3.0V, Vin ≥ 0V, CS# ≥ Vcc-0.2V
		-	-	3	µA	~+40°C	
		-	-	8	µA	~+70°C	
		-	-	10	µA	~+85°C	
Chip deselect to data retention time	t_{CDR}	0	-	-	ns	See retention waveform.	
Operation recovery time	t_R	5	-	-	ms		

Note 1. Typical parameter indicates the value for the center of distribution at 3.0V (Ta= 25ºC), and not 100% tested.
2. CS# controls address buffer, WE# buffer, OE# buffer and Din buffer. If CS# controls data retention mode, Vin levels (address, WE#, OE#, DQ) can be in the high impedance state.

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Low Vcc Data Retention Timing Waveforms

CS# Controlled



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Revision History	R1LP5256E Series Data Sheet

Rev.	Date	Description	
		Page	Summary
1.00	2011.04.13	-	First Edition issued

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